NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G

Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.43$ V at $I_F = 5$ A

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

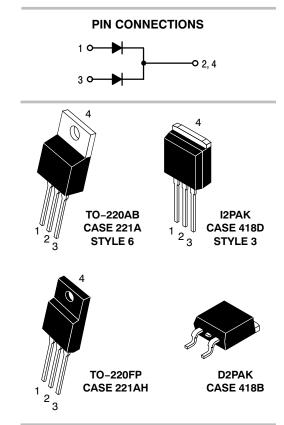
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



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VERY LOW FORWARD VOLTAGE, LOW LEAKAGE SCHOTTKY BARRIER RECTIFIERS 40 AMPERES, 120 VOLTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	120	V
Average Rectified Forward Current (Rated V_R , T_C = 120°C)	Per device Per diode	I _{F(AV)}	40 20	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 125°C)	Per device Per diode	I _{FRM}	80 40	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	250	A
Operating Junction Temperature		ТJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

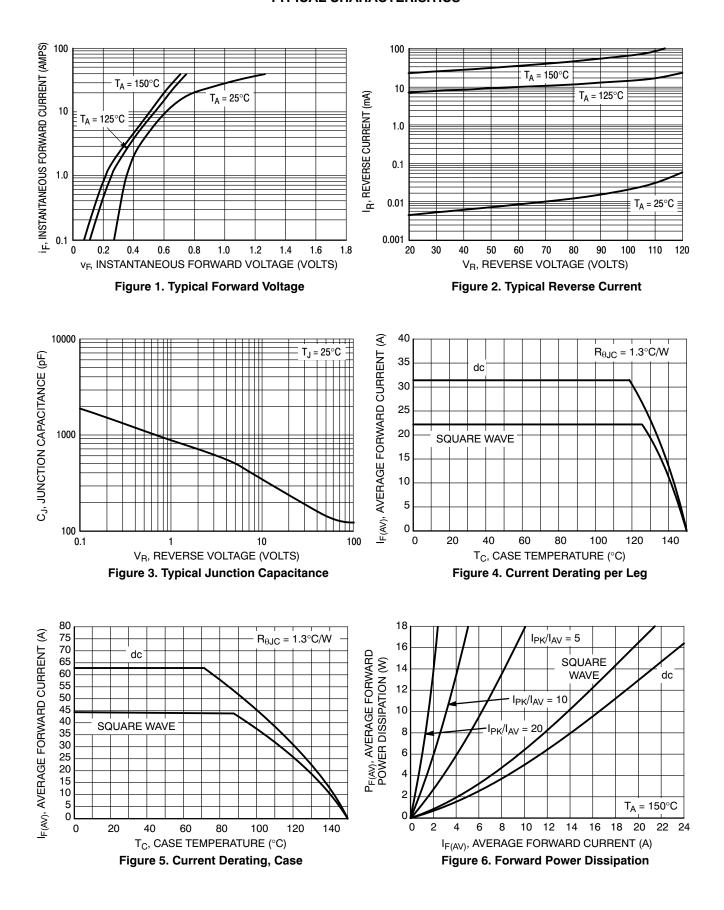
Rating	Symbol	NTST40120CTG, NTSB40120CT-1G	NTSB40120CTG	NTSJ40120CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	1.3 70	0.79 46.3	4.0 105	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

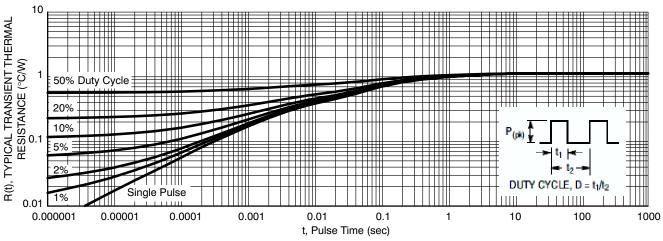
Rating	Symbol	Тур	Мах	Unit
	۷F	0.50 0.60 0.78	- - 0.91	V
$(I_F = 5 A, T_J = 125^{\circ}C)$ $(I_F = 10 A, T_J = 125^{\circ}C)$ $(I_F = 20 A, T_J = 125^{\circ}C)$		0.43 0.53 0.63	_ _ 0.71	
	I _R	16 16		μA mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		_ 30	500 100	μA mA

1. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \leq 2.0%

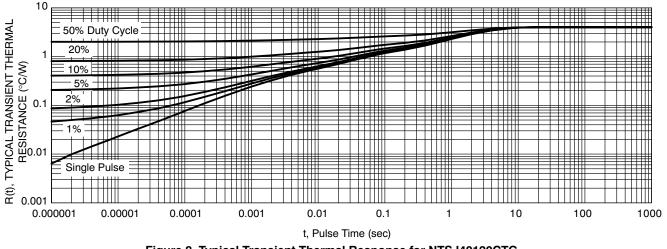
NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G TYPICAL CHARACTERISITICS



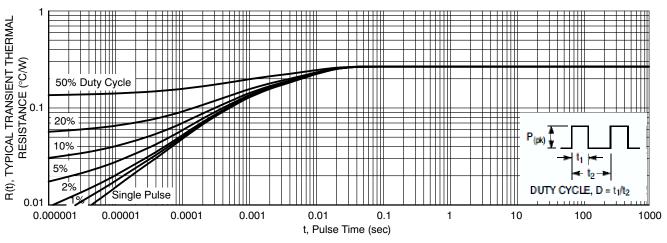
NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G TYPICAL CHARACTERISITICS













NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G

ORDERING INFORMATION

Device	Package	Shipping	
NTST40120CTG	TO-220AB (Pb-Free)	50 Units / Rail	
NTSJ40120CTG	TO-220FP (Halide-Free)	50 Units / Rail	
NTSB40120CT-1G	I ² PAK (Pb–Free)	50 Units / Rail	
NTSB40120CTG	D ² PAK (Pb–Free)	50 Units / Rail	
NTSB40120CTT4G	D ² PAK (Pb–Free)	800 / Tape & Reel	

AYWW AYWW TS40120CG AYWW AYWW TS40120CG TS40120Cx TS40120CG AKA AKA AKA AKA 1 J J $\overline{11}$ TO-220AB I²PAK D²PAK TO-220FP

MARKING DIAGRAMS

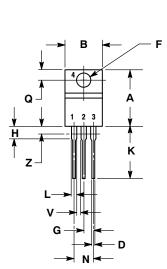
А = Assembly Location

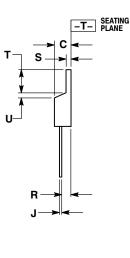
<i>'</i> ``	- / 000011
Y	= Year

- ww = Work Week
- = Polarity Designator AKA
- х = G or H
- = Pb-Free Package G
- н = Halide-Free Package



NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS





TO-220 CASE 221A-09 **ISSUE AF**

NOTES:

3.

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.

DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

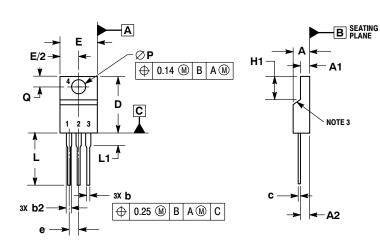
	INCHES		MILLIMETE	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

STYLE 6:

PIN 1. ANODE 2. CATHODE 2. 3. ANODE

4 CATHODE

TO-220 FULLPACK, 3-LEAD CASE 221AH **ISSUE B**



NOTES:

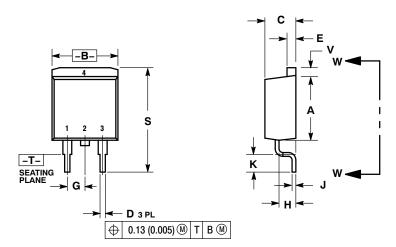
DIES:
DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS.
CONTOUR UNCONTROLLED IN THIS AREA.
DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE

- PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
- 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.30	4.70	
A1	2.50	2.90	
A2	2.50	2.70	
b	0.54	0.84	
b2	1.10	1.40	
C	0.49	0.79	
D	14.70	15.30	
Е	9.70	10.30	
е	2.54	BSC	
H1	6.70	7.10	
L	12.70	14.73	
L1		2.80	
Р	3.00	3.40	
Q	2.80	3.20	

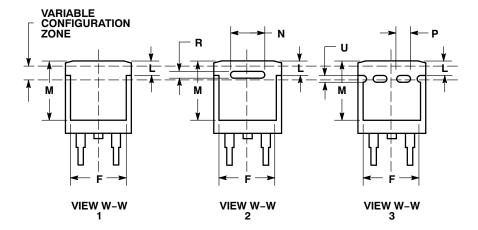
NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS

D²PAK 3 CASE 418B-04 ISSUE K

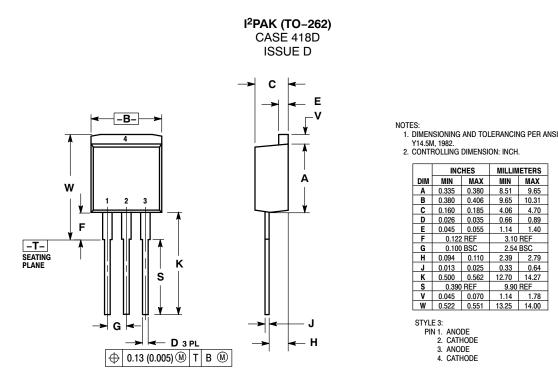


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
в	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
Е	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
к	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
Μ	0.280	0.320	7.11	8.13
Ν	0.197 REF		5.00	REF
Р	0.079 REF		2.00 REF	
R	0.039 REF		0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40



NTST40120CT, NTSJ40120CTG, NTSB40120CT–1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS



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MILLIMETERS

9.65

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4.06

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1.14

2.39 2.79

9.90 REF

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